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With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



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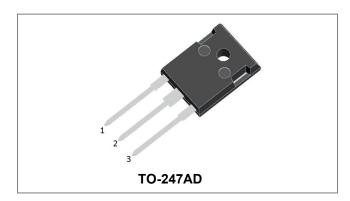








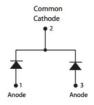
## **MBR60100WT SCHOTTKY RECTIFIER**



#### **Features**

- 150 °C T<sub>J</sub> operation
- Low forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- This is a Pb Free Device
- . All SMC parts are traceable to the wafer lot
- · Additional testing can be offered upon request

#### **Circuit Diagram**



#### **Applications**

- Switching power supply
- Converters
- Free-Wheeling diodes
- Reverse battery protection
- Center tap configuration

#### **Maximum Ratings:**

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V <sub>RRM</sub> V <sub>RWM</sub> V <sub>R</sub>	-	100	V
Average Rectified Forward Current	I <sub>F (AV)</sub>	50% duty cycle @Tc=135°C, rectangular wave form	30(Per Leg) 60(Per Device)	Α
Peak One Cycle Non-Repetitive Surge Current(Per Leg)	I <sub>FSM</sub>	8.3ms, Half Sine pulse	280	Α

#### **Electrical Characteristics:**

Characteristics	Symbol	Condition	Тур.	Max.	Units
Forward Voltage Drop	V <sub>F1</sub>	@ 30A, Pulse, T <sub>J</sub> = 25℃	0.85	0.90	V
(Per Leg)*	V <sub>F2</sub>	@ 30A, Pulse, T <sub>J</sub> = 125℃	0.76	0.81	V
Reverse Current	I <sub>R1</sub>	@V <sub>R</sub> = rated V <sub>R</sub> ,T <sub>J</sub> = 25 ℃	0.01	1.0	mA
(Per Leg)*	I <sub>R2</sub>	@V <sub>R</sub> = rated V <sub>R</sub> ,T <sub>J</sub> = 125℃	8	20	mA
Junction Capacitance(Per Leg)	Ст	$@V_R = 5V, T_C = 25^{\circ}C,$ $f_{SIG} = 1MHz$	400	1200	pF
Voltage Rate of Change	dv/dt	-	-	10,000	V/μs

 $<sup>^*</sup>$  Pulse width < 300  $\mu$ s, duty cycle < 2%

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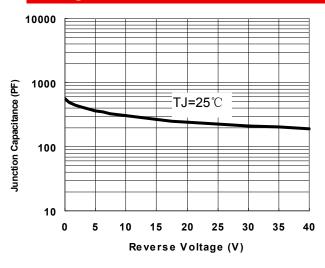




## **Thermal-Mechanical Specifications:**

Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	TJ	-	-55 to +150	°C
Storage Temperature	T <sub>stg</sub>	-	-55 to +150	°C
Typical Thermal Resistance Junction to Case	R <sub>θ</sub> JC	DC operation	2.0	°C/W
Typical Thermal Resistance Junction to Ambient	$R_{ heta JA}$	DC operation	50	°C/W
Typical Thermal Resistance Case to Heat Sink	R <sub>0</sub> CS	Mounting surface,smooth and greased	0.50	°C/W
Approximate Weight	wt	-	6.28	g
Case Style	TO-247AD			

### **Ratings and Characteristics Curves**



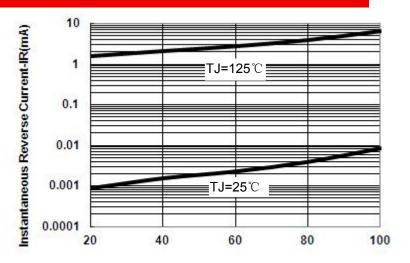


Fig.1-Typical Junction Capacitance

Percent of Rated Peak Reverse Voltage (%)
Fig.2-Typical Reverse Characteristics

TJ=125°C

TJ=25°C

TJ=25°C

TJ=25°C

TJ=25°C

TJ=25°C

Fig.3-Typical Instantaneous Forward Voltage Characteristics

Forward Voltage Drop (V)

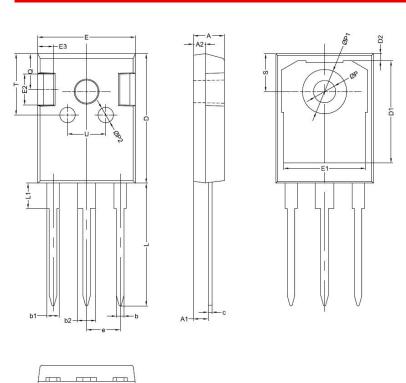
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## **Mechanical Dimensions TO-247AD**



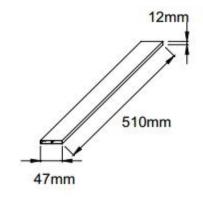
OVMDOL	Millimeters				
SYMBOL	MIN.	TYP.	MAX.		
Α	4.80	5.00	5.20		
A A1	2.20	2.41	2.61		
A2	1.90	2.00	2.10		
b	1.10	1.20	1.40		
b1	1.80	2.00	2.20		
b2	2.80	3.00	3.20		
С	0.50	0.60	0.75		
D	20.30	21.00	21.20		
D1		16.55			
D2		1.20			
Ш	15.45	15.80	16.00		
E1		13.30			
E2		5.00			
E3		2.50			
е		5.44			
L	19.42	19.92	20.70		
L1		4.13			
Р	3.50	3.60	3.70		
P1	7.1		7.40		
P2		2.50			
		5.80			
Q S T	6.05	6.15	6.25		
T		10.00			
U		6.20			

#### **Ordering Information:**

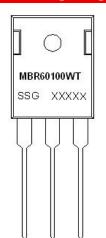
Device	Package	Shipping	
MBR60100WT	TO-247AD(Pb-Free)	25pcs / tube	

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

## **Tube Specification**



# **Marking Diagram**



Where XXXXX is YYWWL

MBR = Device Type 60 = Forward Current (60A) 100 = Reverse Voltage (100V) WT = Configuration

WI = Configuration
SSG = SSG
YY = Year
WW = Week
L = Lot Number

Cautions: Molding resin

Epoxy resin UL:94V-0

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